

Spectrum Devices Corporation

Semiconductor Engineering and Manufacturing

RF & MICROWAVE TRANSISTORS HF SSB APPLICATIONS

HF50-220

FEATURES:

- 30 MHz
- 50 Volts
- IMD −30 dB
- Common Emitter
- Gold Metallization
- P_{out}= 220W PEP Min. with 13 dB Gain
- Improved Collector-Base Breakdown Voltage: 175 Volts Min.
- Direct replacement for ST SD1731 (TH562)



0.500" DIAMETER SOE PACKAGE

DESCRIPTION:

The HF50-220 is a 50V epitaxial silicon NPN planar transistor designed primarily for SSB communications. This device utilizes emitter ballasting to achieve extreme ruggedness under severe operating conditions. The HF50-series products utilize the unique Spectrum Devices' Bipolar process which offers a 60% improvement in collector-base breakdown voltage, enhancing reliability while maintaining RF performance

ABSOLUTE MAXIMUM RATINGS: $(T_{CASE} = 25^{\circ}C)$

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	175	V
V_{CEO}	Collector-Emitter Voltage	55	\mathbf{V}
V _{EBO}	Emitter-Base Voltage	4.0	V
$I_{\rm C}$	Device Current	12	A
P _{DISS}	Total Dissipation	320	W
T_{J}	Junction Temperature	+200	°C
T _{STG}	Storage Temperature	-65 to +150	°C

THERMAL DATA:

R _{TH(J-C)}	Thermal Resistance Junction-case	0.7	°C/W
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$\underline{ELECTRICAL\ SPECIFICATIONS}\ (T_{CASE}=25^{\circ}C)$

DC CHARACTERISTICS

Symbol	Test Conditions		Value			TT . *4
			Min.	Тур.	Max.	Unit
BV_{CBO}	$I_{\rm C} = 200 \text{ mA}$	$I_E = 0 mA$	175			V
BV _{CES}	$I_{\rm C} = 200 \text{ mA}$	$\mathbf{V}_{\mathrm{BE}} = 0 \; \mathbf{V}$	175		•	V
BV _{CEO}	$I_C = 200 \text{ mA}$	$I_B = 0 mA$	55			V
BV _{EBO}	$I_{\rm E} = 20 \text{ mA}$	$I_C = 0 \text{ mA}$	4.0			V
I _{CEO}	$V_{CE} = 30 \text{ V}$	$I_E = 0 \text{ mA}$			5	mA
I _{CES}	$V_{CE} = 55 \text{ V}$	$I_E = 0 mA$			10	mA
$\mathbf{h}_{\mathbf{FE}}$	$V_{CE} = 6 V$	$I_C = 10 A$	15		80	

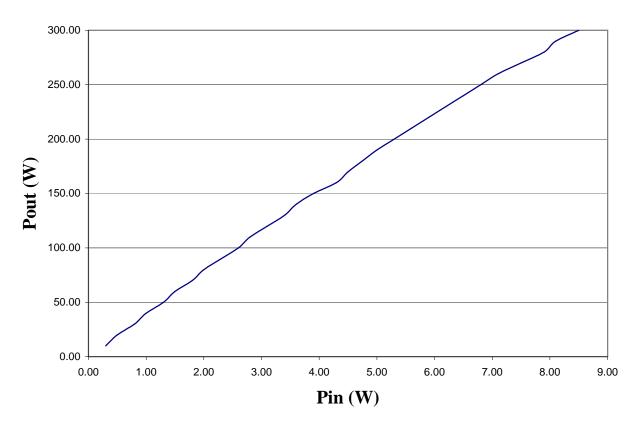
RF CHARACTERISTICS

<i>a</i>			Value				
Symbol	Test Conditions			Min.	Typ.	Max.	Unit
P _{OUT}	f = 30 MHz	$V_{\rm CC} = 50 \ m V$	$I_{CQ} = 150 \text{ mA}$	220	250		W PEP
G_{P}	P _{out} =220 W PEP	$V_{\rm CC} = 50 \ m V$	$I_{CQ} = 150 \text{ mA}$	13			dB
IMD*	P _{out} =220 W PEP	$V_{\rm CC} = 50 \text{ V}$	$I_{CQ} = 150 \text{ mA}$			-30	dBc
η_{C}	P _{out} =220 W PEP	$V_{\rm CC} = 50 \text{ V}$	$I_{CQ} = 150 \text{ mA}$	40			%
C _{OB}	f = 1 MHz	$V_{CB} = 50 V$			330		pF

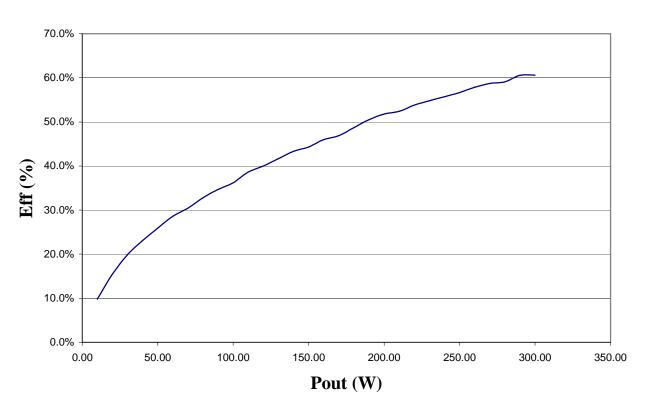
*Conditions f1 = 30.00MHz f2 = 30.001MHz

TYPICAL PERFORMANCE

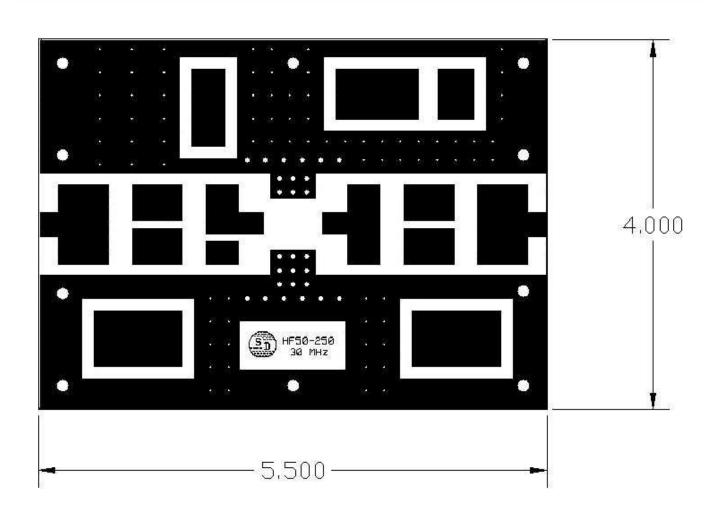
Power Output vs Power Input



Collector Efficiency vs Power Out

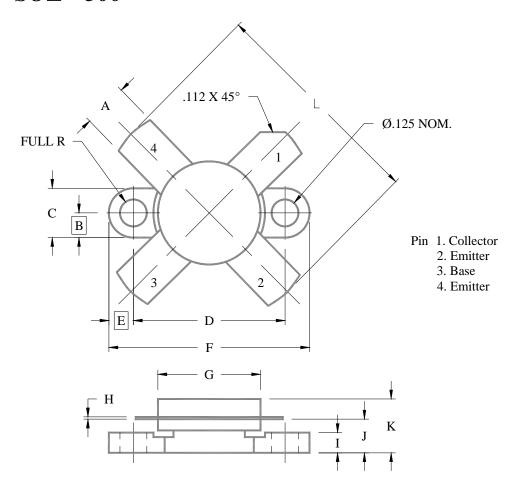


PCB BOARD LAYOUT



PACKAGE MECHANICAL DATA

SOE - 500



	Minimum	Maximum		Minimum	Maximum
	Inches/MM	Inches/MM		Inches/MM	Inches/MM
A	.220/5.59	.230/5.84	G	.495/12.57	.505/12.83
В	.125	7/3.18	Н	.003/0.08	.007/0.18
С	.245/6.22	.255/6.48	I	.090/2.29	.110/2.79
D	.720/18.28	.730/18.54	J	.160/4.06	.175/4.45
Е	.125	7/3.18	K		.280/7.11
F	.970/24.64	.980/24.89	L		1.050/26.67

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